

PATENT APPLICATION

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re application of Docket No: Q80822
Masatomo SHIBATA Allowed: June 21, 2007
Appln. No.: 10/813,176 Group Art Unit: 2813
Confirmation No.: 4446 Examiner: Jennifer M. Dolan
Filed: March 31, 2004
For: III-V NITRIDE SEMICONDUCTOR SUBSTRATE AND ITS PRODUCTION METHOD

AMENDMENT UNDER 37 C.F.R. §1.312

MAIL STOP ISSUE FEE
Commissioner for Patents
P.O. Box 1450
Alexandria, VA 22313-1450

Amend - OK - to enter

JMB 8/30/07

Sir:

Pursuant to the provisions of 37 C.F.R. §1.312, please amend the above-identified application as follows on the accompanying pages.

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